NSN 5962-01-326-7916

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Body Length:
Between 1.435 inches and 1.485 inches
Body Width:
Between 0.515 inches and 0.600 inches
Body Height:
Between 0.120 inches and 0.165 inches
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
End Application:
4935-00-930-7250 test station, gu
Features Provided:
Hermetically sealed and programmed and electrostatic sensitive and ultraviolet erasable and burn in
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.5 volts power source
Time Rating Per Chacteristic:
200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

Yes - demil/mli

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